NSN 5961-01-081-5116

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Inclosure Material:

Plastic

Overall Length:

0.540 inches

Overall Height:

0.190 inches

Overall Width:

0.420 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

80.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between 3.00 amperes source cutoff current and 6.00 amperes source cutoff current

Power Rating Per Characteristic:

2.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

75.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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